

30A 600V Fast recovery diode

1 Description

30A, 600V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink. TO-220F series comply with UL standards (File ref:E252906).

2 Features

- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25°C, unless otherwise noted)

(1) K — A (2)	$V_{BR} = 600V$ $V_{F(single)(Max)} = 1.80V$ $I_{F(AV)(single)} = 30A$				
TO-220F-2L Insulated	TO-220-2L				
TO-247-2L					

PARAMETER	SYMBOL	VALUE	UNIT	
Peak Repetitive Reverse Voltage		V _{RRM}	600	V
Working Peak Reverse Voltage		V _{RWM}	600	V
DC Blocking Voltage		V _R	600	V
Average Rectified Forward Current(single)	TO-220/TO-247(Tc=135℃) TO-220F(Tc=100℃)	I _{F(AV)}	30	А
Repetitive Peak Surge Current(single)		I _{FRM}	45	А
Nonrepetitive Peak Surge Current(single) t=8.3ms		I _{FSM}	300	А
Avalanche Energy(single) L=1mH		E _{AS}	80	mJ
Operating Junction Temperature Range	Tj	-55~150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE			UNIT
FARAMETER	STMDUL	TO-220	TO-220F	TO-247	UNIT
Thermal Resistance, Junction to Case-sink	RthJC	1.50	2.50	1.0	°C/W



MUR3060

4.3 Electrical Characteristics (Tc=25[°]C, unless otherwise noted)

PARAMETER SYMBOL TEST CONDITION		TEST CONDITION	MIN	TYP	MAX	UNIT
		I _F = 20A	-	1.45	1.70	V
Maximum Instantaneous	VF	I _F = 30A	-	1.55	1.80	V
Forward Voltage		I _F = 30A, T _C = 150℃	-	-	1.60	V
		I _F = 40A	-	1.56	1.90	V
Maximum Instantaneous	IR	V _R = 600V	-	-	5	uA
Reverse		V _R = 600V, T _C = 150℃	-	-	1	mA
Maximum Reverse Recovery Time	trr	V _R =30V I _F =1A -d _{l/dt} =50A/us	-	35	50	ns
Total capacitance	Ctot	V _R =0V f=1MHz	-	680	-	pF
DC Blocking Voltage	V _{BR}	I _R =100uA	610	-	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

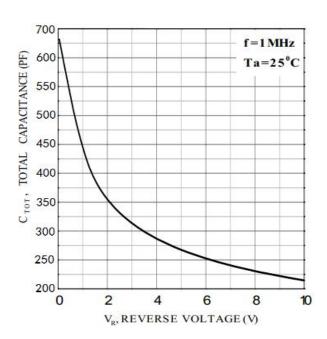


FIGURE 1. Total capacitance vs Voltage

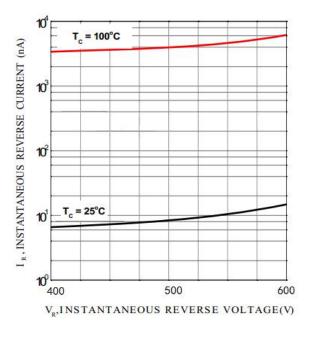
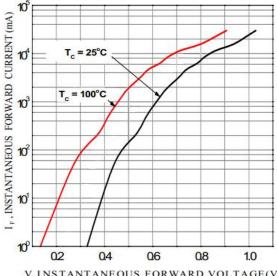


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE







 $V_{\!_{F}}, INSTANTANEOUS \ FOR WARD \ VOLTAGE(V) \\ FIGURE 3. FORWARD \ CURRENT vs \ FORWARD \ VOLTAGE$

6 Typical Test Circuit and Waveform

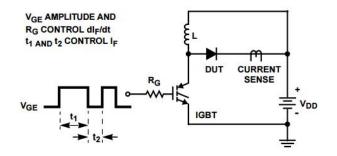
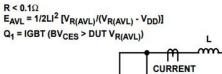
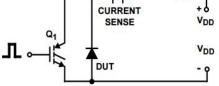


FIGURE 5. trr TEST CIRCUIT





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FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

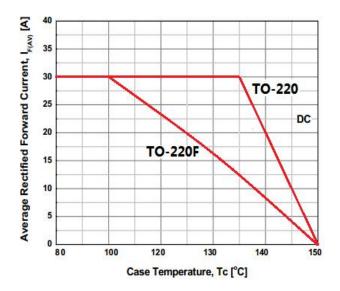


FIGURE 4. CURRENT DERATING CURVE

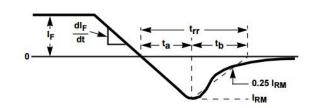


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

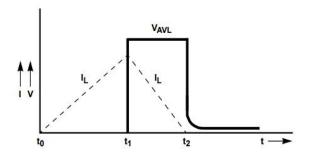


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Specifications and Packaging Models

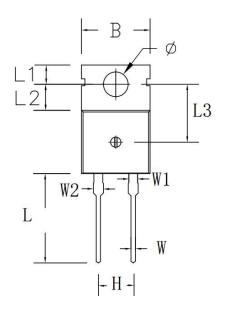
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Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MUR3060	TO-220C	MUR3060	Pb-free	Tube	1000/box
MURF3060	TO-220F	MURF3060	Pb-free	Tube	1000/box
MUR3060	TO-247	MUR3060	Pb-free	Tube	300/box

8 Dimensions

TO-220C-2L PACKAGE OUTLINE DIMENSIONS

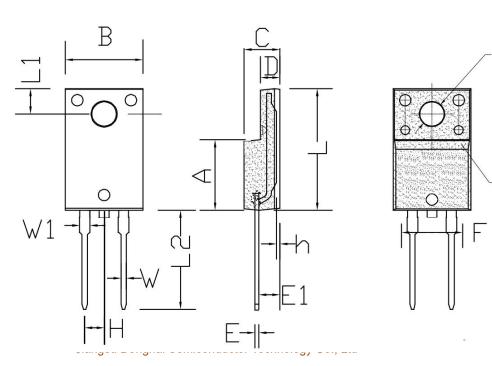


	Camb a 1	Dimensions In	Millimeters	Dimensions	In Inches
	Symbol	min.	max.	min.	max.
	А	8.80	9.30	0.346	0.366
	В	9.70	10.30	0.382	0.406
	С	4.25	4.75	0.167	0.187
<u> </u>	D	1.20	1.45	0.047	0.057
	Е	0.40	0.60	0.016	0.024
·Α [Н	5.08	ТҮР	0.201	TYP
1 [W	0.60	0.95	0.024	0.037
[W1	1.05	1.45	0.041	0.057
	W2	1.20	1.60	0.047	0.063
	L	12.60	13.40	0.496	0.528
	L1	2.45	2.95	0.096	0.116
-	L2	3.45	3.95	0.136	0.156
E [L3	8.15	8.65	0.321	0.341
	Φ	3.50	3.90	0.138	0.154

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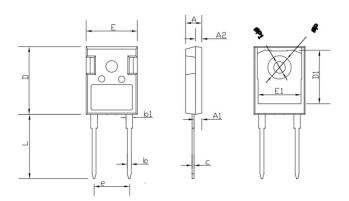
TO-220F-2L PACKAGE OUTLINE DIMENSIONS



Symbol	DimensionsIn	Millimeters
Symbol	min.	max.
А	7.90	8.50
В	10.00	10.50
С	4.30	4.90
D	2.80	3.20
L	14.80	15.30
h	0.40	0.60
L1	2.90	3.40
L2	12.65	13.45
W	0.60	0.80
W1	1.15	1.55
Н	2.54	TYP
Е	0.60	0.70
φ	2.90	3.40
E1	2.40	2.90
F	7.75	8.25



TO-247-2L PACKAGE OUTLINE DIMENSIONS



0 1 1	Dimensions 1	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	4.90	5.10	0.193	0.201
A1	2.31	2.51	0.091	0.099
A2	1.90	2.10	0.075	0.083
b	1.16	1.26	0.046	0.050
b1	1.96	2.06	0.0772	0.0812
с	0.59	0.66	0.0232	0.0260
D	20.90	21.10	0.8235	0.8313
D1	16.25	16.85	0.6403	0.6639
E	15.70	15.90	0.6186	0.6265
E1	13.10	13.50	0.5161	0.5319
е		10.88E	BCS	
L	19.80	20.10	0.7801	0.7919
ΦР	3.50	3.70	0.1379	0.1458
Φ Ρ1	0	7.30	0	0.2876

9 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

10 Appendix

Revision history:

Date	REV.	Description	Page
2017.03.31	1.0	Original	